

**PI6C492150xTQ**

**High Performance Automotive 2/4 Ports LVDS Fanout Buffer**

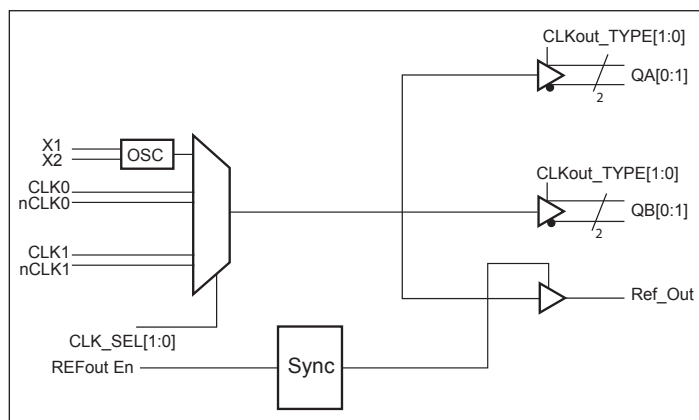
## Description

The DIODES PI6C492150xTQ is an automotive high-performance LVDS fanout buffer device which supports up to 1.5GHz frequency. This device is ideal for systems that need to distribute low-jitter clock signals to multiple destinations.

## Application(s)

- Networking Systems, including Switches and Routers
- High-Frequency Backplane-based Computing and Telecom Platforms
- ADAS
- Automotive Infotainment

## Block Diagram



## Features

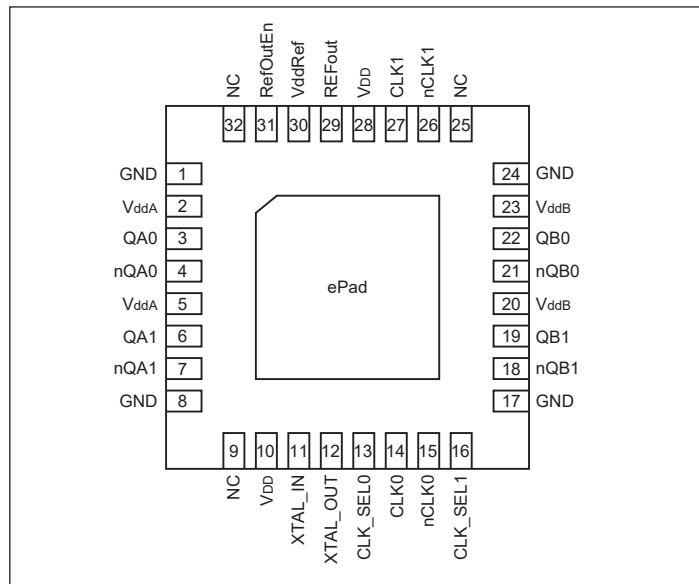
- 2/4 LVDS Outputs with 2 Banks
- LVCMOS Reference Output Up to 200MHz
- Up to 1.5GHz Output Frequency for Differential Outputs
- Ultra-low Additive Phase Jitter: <0.03ps (differential 156.25MHz, 12KHz to 20MHz integration range)
- Selectable Reference Inputs Support either Single-ended or Differential or Xtal
- Low Skew Between Outputs within Banks (<40ps)
- Low Delay from Input to Output (Tpd typ. <1.5ns)
- Separate Input Output Supply Voltage for Level Shifting
- 2.5V / 3.3V Power Supply
- AEC-Q100 Qualified, Automotive Grade 1 Support
- Ambient Operating Temperature: -40°C to 125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The PI6C492150xTQ is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.  
<https://www.diodes.com/quality/product-definitions/>
- Packaging (Pb-free & Green):
  - 32-pin WQFN (ZHW)

## Notes:

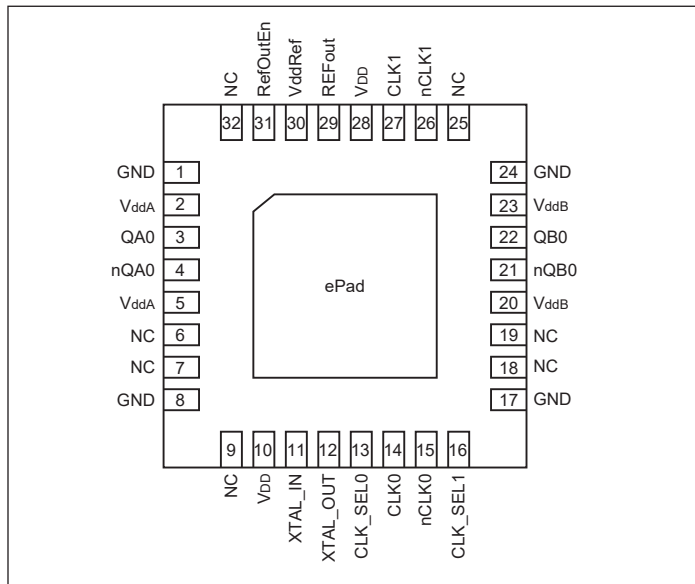
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q100 qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.

## Pin Configuration

**PI6C4921504TQ**



**PI6C4921502TQ**



## Pin Description

| PI6C4921504TQ<br>Pin # | PI6C4921502TQ<br>Pin#   | Pin Name         | Type   | Description  |
|------------------------|-------------------------|------------------|--------|--|
| 1, 8, 17, 24           | 1, 8, 17, 24            | GND              | Power  | Negative power supply  |
| 9, 25, 32              | 6, 7, 9, 18, 19, 25, 32 | NC               | -      | Not Connect  |
| 2, 5                   | 2, 5                    | V <sub>ddA</sub> | Power  | Power supply for Bank A Output buffers. V <sub>ddA</sub> operates from 3.3V or 2.5V      |
| 13                     | 13                      | CLK_SEL0         | Input  | Clock input source selection pin   |
| 16                     | 16                      | CLK_SEL1         | Input  | Clock input source selection pin   |
| 14,<br>15              | 14,<br>15               | CLK0<br>nCLK0    | Input  | Differential clock input   |
| 27,<br>26              | 27,<br>26               | CLK1<br>nCLK1    | Input  | Differential clock input   |
| 11                     | 11                      | XTAL_In          | Input  | Input for crystal, XO, or single ended clock   |
| 12                     | 12                      | XTAL_Out         | Output | Output for crystal. Leave Xtal_Out floating if Xtal_In is driven by a single ended clock |
| 10, 28                 | 10, 28                  | V <sub>DD</sub>  | Power  | Power supply for core  |
| 18,<br>19              | —                       | nQB1<br>QB1      | Output | Differential output clock  |
| 21,<br>22              | 21,<br>22               | nQB0<br>QB0      | Output | Differential output clock  |

**PI6C492150xTQ**

| PI6C4921504TQ<br>Pin # | PI6C4921502TQ<br>Pin# | Pin Name         | Type   | Description  |
|------------------------|-----------------------|------------------|--------|--|
| 29                     | 29                    | Ref_Out          | Output | Reference output clock   |
| 7,<br>6                | —                     | nQA1<br>QA1      | Output | Differential output clock  |
| 4,<br>3                | 4,<br>3               | nQA0<br>QA0      | Output | Differential output clock  |
| ePad                   | ePad                  | ePad             | GND    | Connect to the PCB ground  |
| 20, 23                 | 20, 23                | V <sub>ddB</sub> | Power  | Power supply for Bank B Output buffers. V <sub>ddB</sub> operates from 3.3 V or 2.5V |
| 30                     | 30                    | VddRef           | Power  | Power supply for reference clock output  |
| 31                     | 31                    | RefOutEn         | Input  | REFout enable input  |

## Function Table

Table 1: Input Selection

| CLK_SEL1 | CLK_SEL0 | Selected Input |
|----------|----------|----------------|
| 0        | 0        | CLK0, nCLK0    |
| 0        | 1        | CLK1, nCLK1    |
| 1        | X        | XTAL_In        |

Table 2: Reference Output Enable

| REFout_EN | REFout STATE    |
|-----------|-----------------|
| 0         | Disabled (Hi-Z) |
| 1         | Enabled         |

Table 3: CLKx Input vs. Output States

| State of Selected Input Clock             | State of Enabled Outputs           |
|---|------------------------------------|
| CLKx and nCLKx<br>Inputs Floating         | Logic Low                          |
| CLKx and nCLKx<br>Inputs Shorted Together | Not Supported. Output is Undefined |
| CLKx Logic Low                            | Logic Low                          |
| CLKx Logic High                           | Logic High                         |

## Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested)

|  |                       |
|--|-----------------------|
| Storage Temperature.....                                       | -55 to +150°C         |
| Supply Voltage to Ground Potential ( $V_{DD}$ , $V_{DDO}$ )... | -0.5 to +4.6V         |
| Inputs (Referenced to GND) .....                               | -0.5 to $V_{DD}+0.5V$ |
| Clock Output (Referenced to GND).....                          | -0.5 to $V_{DD}+0.5V$ |
| Latch Up .....   | 200mA                 |
| ESD Protection (Input) .....                                   | 2000V min (HBM)       |
| Junction Temperature .....                                     | 150 °C max            |

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Power Supply Characteristics and Operating Conditions

| Symbol    | Parameter                                    | Test Condition        | Min.  | Typ. | Max.  | Units |
|-----------|--|-----------------------|-------|------|-------|-------|
| $V_{DD}$  | Core Supply Voltage                          |                       | 2.375 |      | 3.465 | V     |
| $V_{DDO}$ | Output Supply Voltage                        | $V_{DDO} \leq V_{DD}$ | 2.375 |      | 3.465 | V     |
| $I_{DD}$  | Core Power Supply Current                    | All LVDS Loaded       |       | 50   | 65    | mA    |
| $I_{DDO}$ | Output Power Supply Current                  | All LVDS Loaded       |       | 35   | 46    |       |
| $T_A$     | Ambient Operating Temperature <sup>(1)</sup> | LVDS output           | -40   |      | 125   | °C    |

Note:

1. Either  $T_A$  used as operating condition

## DC Electrical Specifications - Differential Inputs

| Symbol      | Parameter                          | Test Condition   | Min. | Typ. | Max.         | Units |
|-------------|------------------------------------|------------------|------|------|--------------|-------|
| $I_{IH}$    | Input High current                 | Input = $V_{DD}$ |      |      | 150          | uA    |
| $I_{IL}$    | Input Low current                  | Input = GND      | -150 |      |              | uA    |
| $C_{IN}$    | Input capacitance                  |                  |      | 3    |              | PF    |
| $V_{IH}$    | Input high voltage                 |                  |      |      | $V_{DD}+0.3$ | V     |
| $V_{IL}$    | Input low voltage                  |                  | -0.3 |      |              | V     |
| $V_{ID}$    | Input Differential Amplitude PK-PK |                  | 0.15 |      | 1.3          | V     |
| $V_{CM}$    | Common mode input voltage          |                  | 0.25 |      | $V_{DD}-1.2$ | V     |
| $ISO_{MUX}$ | MUX isolation                      |                  |      | -89  |              | dBc   |

## DC Electrical Specifications - LVCMOS Inputs

| Symbol   | Parameter          | Conditions       | Min. | Typ. | Max. | Units |
|----------|--------------------|------------------|------|------|------|-------|
| $I_{IH}$ | Input High current | Input = $V_{DD}$ |      |      | 150  | uA    |

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| Symbol   | Parameter          | Conditions      | Min. | Typ. | Max.         | Units |
|----------|--------------------|-----------------|------|------|--------------|-------|
| $I_{IL}$ | Input Low current  | Input = GND     | -150 |      |              | uA    |
| $V_{IH}$ | Input high voltage | $V_{DD} = 3.3V$ | 2.0  |      | $V_{DD}+0.3$ | V     |
| $V_{IL}$ | Input low voltage  | $V_{DD} = 3.3V$ | -0.3 |      | 0.8          | V     |
| $V_{IH}$ | Input high voltage | $V_{DD} = 2.5V$ | 1.7  |      | $V_{DD}+0.3$ | V     |
| $V_{IL}$ | Input low voltage  | $V_{DD} = 2.5V$ | -0.3 |      | 0.7          | V     |

**DC Electrical Specifications- LVDS Outputs**

| Parameter  | Description  | Conditions | Min. | Typ. | Max. | Units |
|------------|--|------------|------|------|------|-------|
| $V_{OH}$   | Output High voltage                                  |            | 1.4  | 1.5  | 1.6  | V     |
| $V_{OL}$   | Output Low voltage                                   |            | 1    | 1.1  | 1.25 | V     |
| $V_{ocm}$  | Output commode voltage                               |            | 1.2  | 1.3  | 1.45 | V     |
| $DV_{ocm}$ | Change in $V_{ocm}$ between completely output states |            |      |      | 50   | mV    |

**DC Electrical Specifications – LVCMOS Outputs**

| Parameter | Description         | Conditions                               | Min. | Typ. | Max. | Units |
|-----------|---------------------|--|------|------|------|-------|
| $V_{OH}$  | Output High voltage | $V_{DDO} = 3.3V \pm 5\%, I_{OH} = -8mA$  | 2.3  |      |      | V     |
|           |                     | $V_{DDO} = 2.5V \pm 5\%, I_{OH} = -8mA$  | 1.5  |      |      | V     |
| $V_{OL}$  | Output Low voltage  | $V_{DDO} = 3.3V \pm 5\%, I_{OL} = 8mA$   |      |      | 0.5  | V     |
|           |                     | $V_{DDO} = 2.5V \pm 5\%, I_{OL} = 8mA$   |      |      | 0.4  | V     |
| $V_{OH}$  | Output High voltage | $V_{DDO} = 3.3V \pm 5\%, I_{OH} = -24mA$ | 2.1  |      |      | V     |
|           |                     | $V_{DDO} = 2.5V \pm 5\%, I_{OH} = -16mA$ | 1.5  |      |      | V     |
| $V_{OL}$  | Output Low voltage  | $V_{DDO} = 3.3V \pm 5\%, I_{OL} = 24mA$  |      |      | 1    | V     |
|           |                     | $V_{DDO} = 2.5V \pm 5\%, I_{OL} = 16mA$  |      |      | 0.8  | V     |

**AC Electrical Specifications – LVDS Outputs**

| Parameter | Description            | Conditions      | Min. | Typ. | Max. | Units |
|-----------|------------------------|-----------------|------|------|------|-------|
| $F_{OUT}$ | Clock output frequency | LVDS            |      |      | 1500 | MHz   |
| $T_r$     | Output rise time       | From 20% to 80% | 100  | 150  | 300  | ps    |
| $T_f$     | Output fall time       | From 80% to 20% | 100  | 150  | 300  | ps    |

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| Parameter             | Description                      | Conditions   | Min. | Typ. | Max. | Units |
|-----------------------|----------------------------------|--|------|------|------|-------|
| T <sub>ODC</sub>      | Output duty cycle                | Frequency < 650MHz,<br>V <sub>ID</sub> ≥ 400mV                   | 47   |      | 53   | %     |
|                       |                                  | Frequency < 1GHz,<br>V <sub>ID</sub> ≥ 400mV                     | 45   |      | 55   |       |
|                       |                                  | Frequency < 1.5GHz,<br>V <sub>ID</sub> ≥ 400mV                   | 40   |      | 60   |       |
| V <sub>PP</sub>       | Output swing Single-ended        | LVDS outputs @ <1GHz   | 250  |      | 600  | mV    |
|                       |                                  | LVDS outputs @ >1GHz   | 250  |      | 550  |       |
| T <sub>j</sub>        | Buffer additive jitter RMS       | 156.25MHz, 12kHz to 20MHz  |      | 0.02 |      | ps    |
|                       |                                  | 156.25MHz, 10kHz to 1MHz   |      | 0.01 |      | ps    |
| T <sub>SK</sub>       | Output Skew                      | 4 outputs devices, outputs in same bank, with same load, at DUT. |      | 15   | 40   | ps    |
| T <sub>PD</sub>       | Propagation Delay                | LVDS @ 3.3V, 100MHz  |      | 570  |      | ps    |
| T <sub>OD</sub>       | Valid to HiZ                     |  |      |      | 200  | ns    |
| T <sub>OE</sub>       | HiZ to valid                     |  |      |      | 200  | ns    |
| T <sub>P2P Skew</sub> | Part to Part Skew <sup>(1)</sup> |  |      | 80   | 120  | ps    |

## AC Electrical Specifications – CMOS

(Operating Temperatures -40°C to 125°C)

| Parameter                       | Description                  | Conditions   | Min. | Typ. | Max. | Units  |
|---------------------------------|------------------------------|--|------|------|------|--------|
| F <sub>OUT</sub>                | Ref_Out frequency            | XTAL input   | 10   |      | 50   | MHz    |
|                                 |                              | Reference input  |      |      | 200  | MHz    |
| T <sub>j</sub>                  | Buffer additive jitter RMS   | XTAL input   |      | 0.3  |      | ps     |
|                                 |                              | Reference input  |      | 0.03 |      | ps     |
| t <sub>r</sub> / t <sub>f</sub> | Rise time, Fall time         | C <sub>L</sub> = 5pF   |      | 0.8  |      | ns     |
| T <sub>ODC</sub>                | Output duty cycle            | C <sub>L</sub> = 5pF<br>3.3V, max test freq. 200MHz<br>2.5V, max test freq. 150MHz | 45   |      | 55   | %      |
| t <sub>PD</sub>                 | Propagation delay            | 3.3V, 25MHz  |      | 4500 |      | ps     |
| t <sub>S</sub>                  | Setup time                   |  | 300  |      |      | ps     |
| t <sub>SOD</sub>                | Clock edge to output disable | Ref_Out  | 2    |      | 4    | cycles |
| t <sub>SOE</sub>                | Clock edge to output enable  | Ref_Out  | 2    |      | 4    | cycles |
| R <sub>IUT</sub>                | Output Impedance             | V <sub>DDO</sub> = 3.3V ± 5%   |      | 30   |      | Ω      |
|                                 |                              | V <sub>DDO</sub> = 2.5V ± 5%   |      | 45   |      | Ω      |

Notes:

1. This parameter is guaranteed by design

## Crystal Characteristics

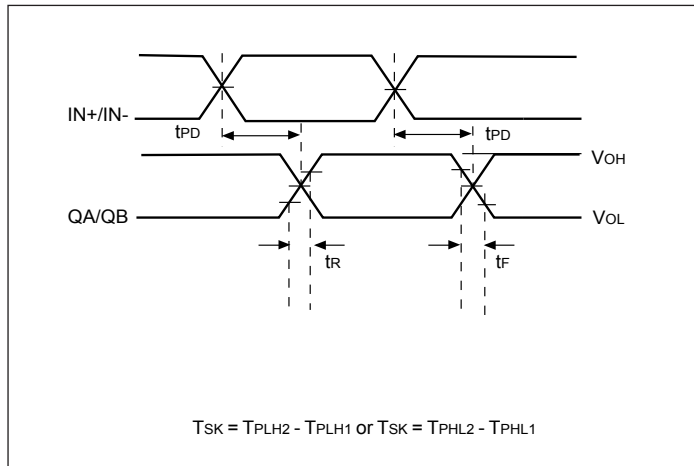
| Parameter                          | Min.        | Typ. | Max. | Units    |
|------------------------------------|-------------|------|------|----------|
| Mode of Oscillation                | Fundamental |      |      |          |
| Frequency Range                    | 10          |      | 50   | MHz      |
| Equivalent Series Resistance (ESR) |             |      | 70   | $\Omega$ |
| Shunt Capacitance                  |             |      | 7    | pF       |
| Load Capacitance                   | 10          |      | 18   | pF       |
| Drive Level                        |             |      | 500  | $\mu$ W  |

## Recommended Crystals

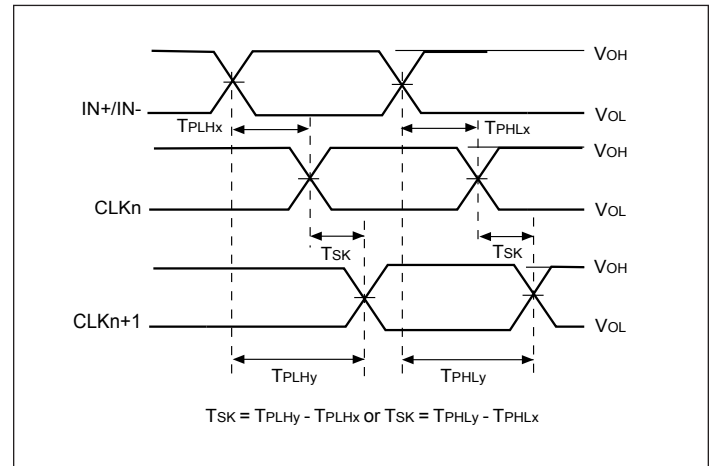
Diodes Recommends:

- a) GC2500003 XTAL 49S/SMD(4.0 mm), 25M, CL=18pF, +/-30ppm  
[http://www.pericom.com/pdf/datasheets/se/GC\\_GF.pdf](http://www.pericom.com/pdf/datasheets/se/GC_GF.pdf)
- b) FY2500091, SMD 5x3.2(4P), 25M, CL=18pF, +/-30ppm  
[http://www.pericom.com/pdf/datasheets/se/FY\\_F9.pdf](http://www.pericom.com/pdf/datasheets/se/FY_F9.pdf)
- c) FL2500047, SMD 3.2x2.5(4P), 25M, CL=18pF, +/-20ppm  
<http://www.pericom.com/pdf/datasheets/se/FL.pdf>

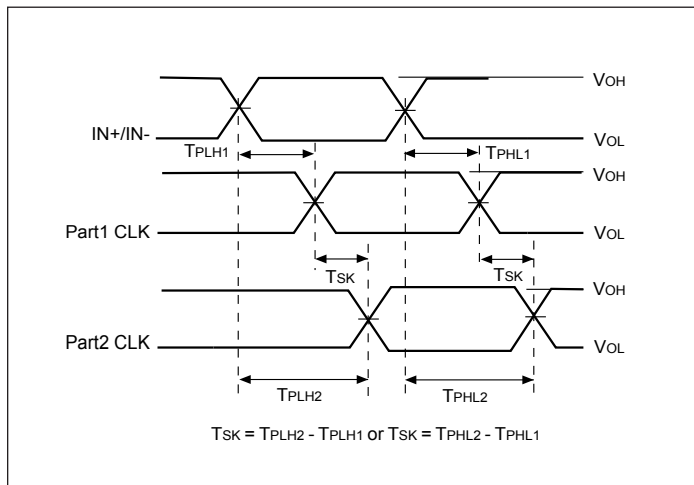
## Propagation Delay ( $T_{PD}$ )



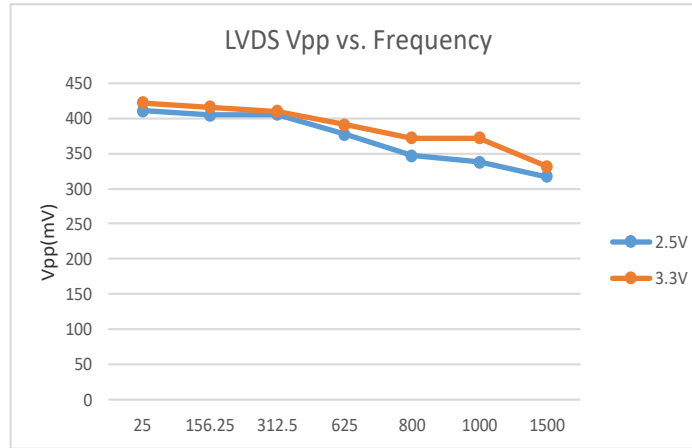
## Output Skew ( $T_{SK}$ )



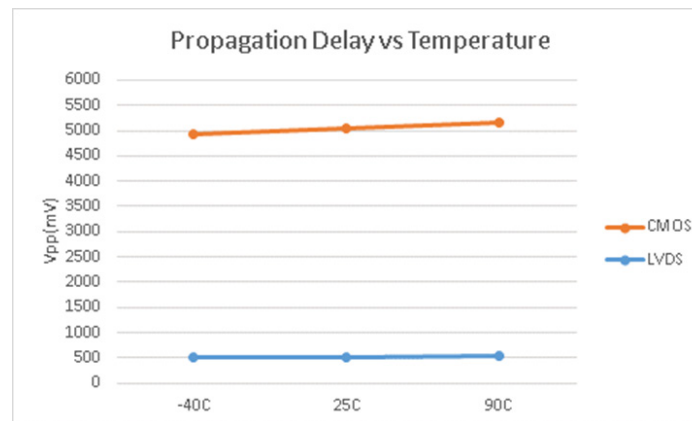
## Part to Part Skew



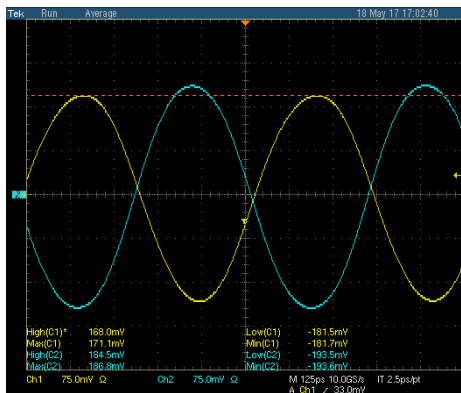
## LVDS Output Swing vs. Frequency



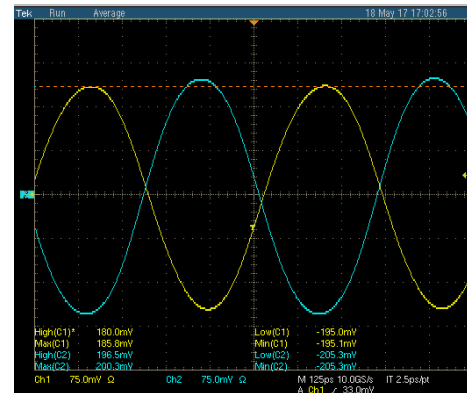
## Propagation Delay vs Temperature



## 1.5GHz LVDS Waveform



2.5V LVDS Waveform



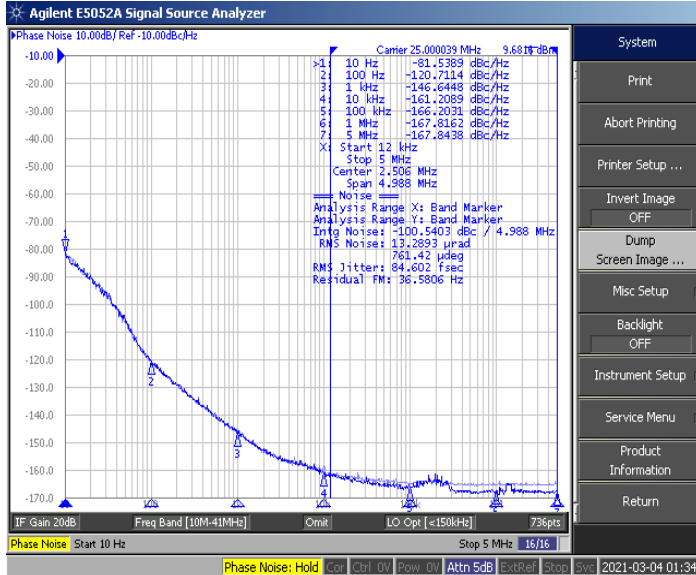
3.3V LVDS Waveform

## Phase Noise and Additive Jitter

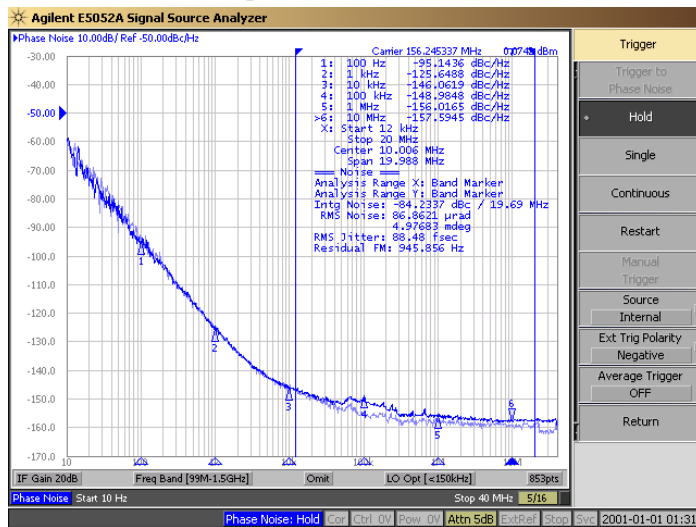
Output phase noise (Dark Blue) vs Input Phase noise (light blue)

Additive jitter is calculated at 25MHz ~71fs RMS (12kHz to 5MHz). Additive jitter =  $\sqrt{(\text{Output jitter}^2 - \text{Input jitter}^2)}$

Ref\_out 25MHz Phase Noise Plot, VDD=VDDO=3.3V, 25°C, Driven by 25MHz CMOS XO



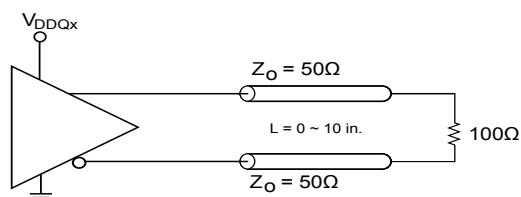
## 156.25M LVDS Output Additive Jitter Noise Plot, 3.3V



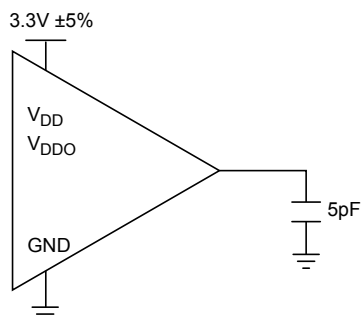
3.3V LVDS Output Jitter 88fs vs. Input 72fs

### Configuration Test Load Board Termination for LVDS Outputs

LVDS Buffer



### Configuration Test Load Board Termination for LVCMOS Outputs



## Application Information

### Wiring the differential input to accept single ended levels

Figure 1 shows how the differential input can be wired to accept single ended levels. The reference voltage  $V_{REF} = V_{DD}/2$  is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the  $V_{REF}$  in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and  $V_{DD} = 3.3V$ ,  $V_{REF}$  should be 1.25V and  $R2/R1 = 0.609$ .

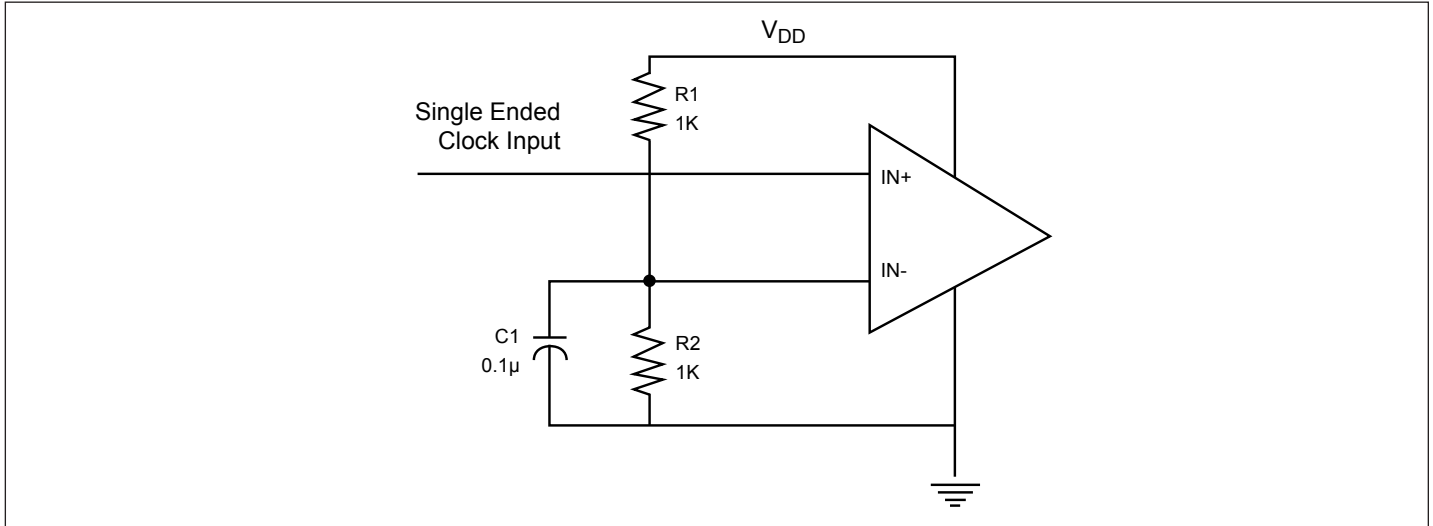
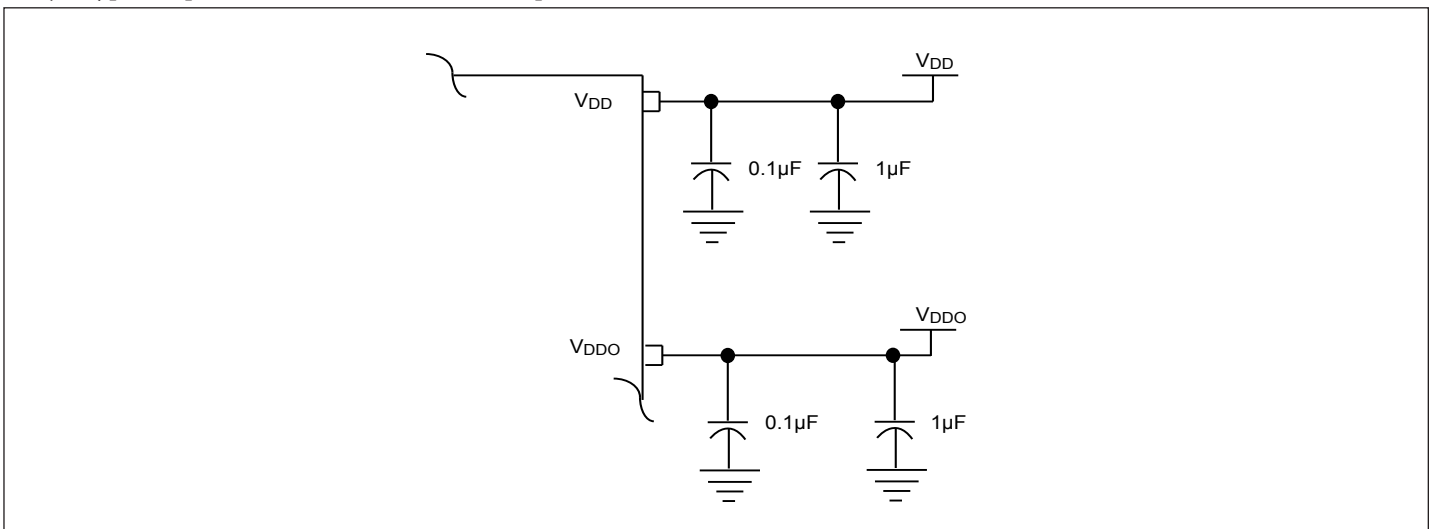


Figure 1. Single-ended Input to Differential Input Device

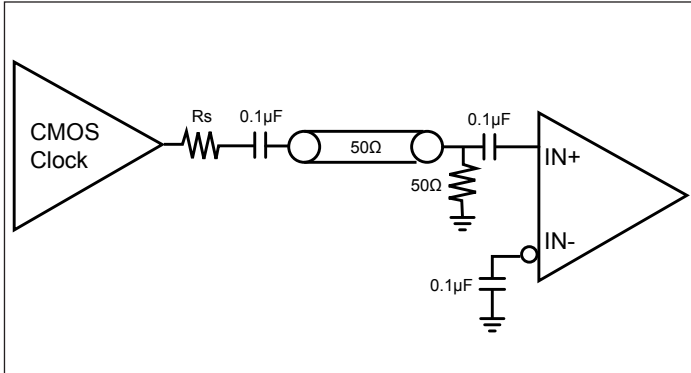
### Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. All power pins should be individually connected to the power supply plane through vias, and 0.1μF and 1μF bypass capacitors should be used for each pin.

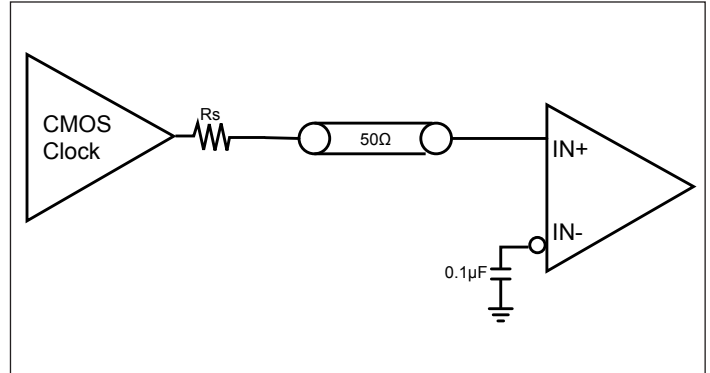


**PI6C492150xTQ**

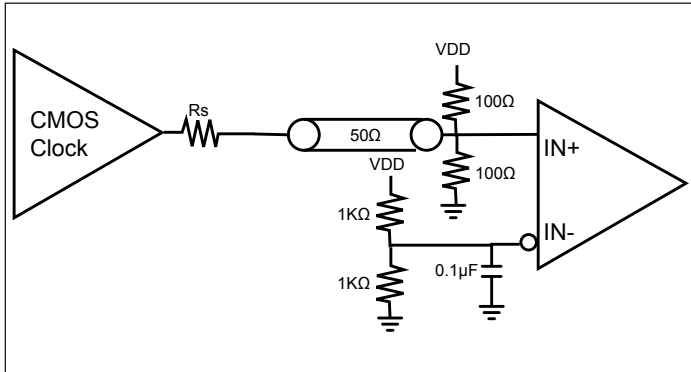
**Single Ended Input, AC Couple**



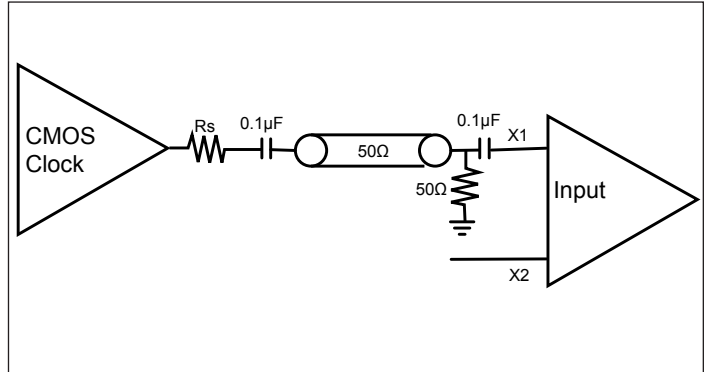
**Single Ended Input, DC Couple**



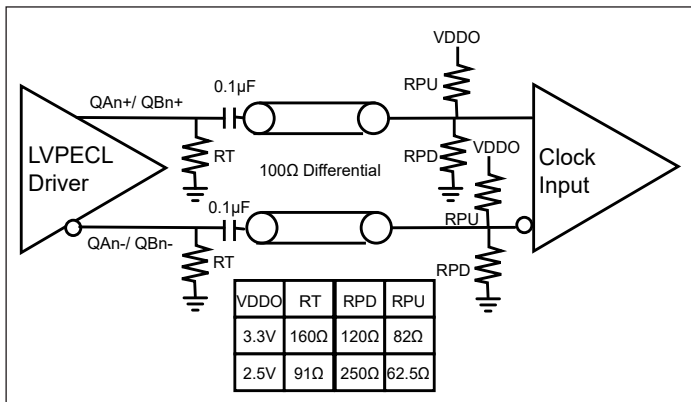
**Single Ended Input, DC Couple**



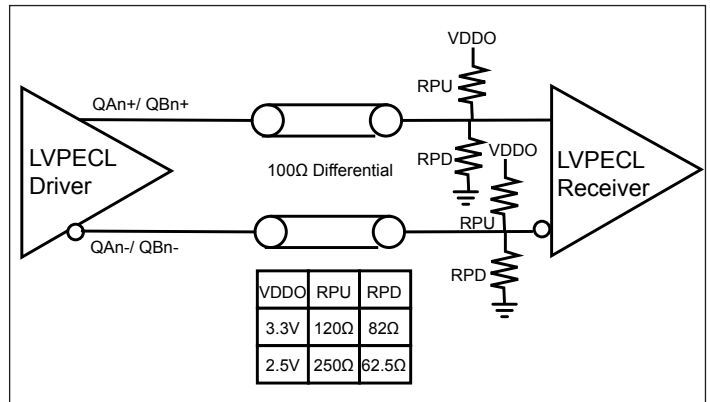
**Driving X1 with a Single Ended Input**



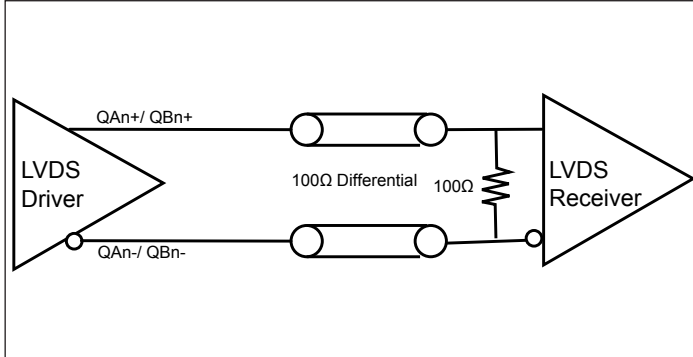
**LVPECL, AC Couple, Thevenin Equivalent**



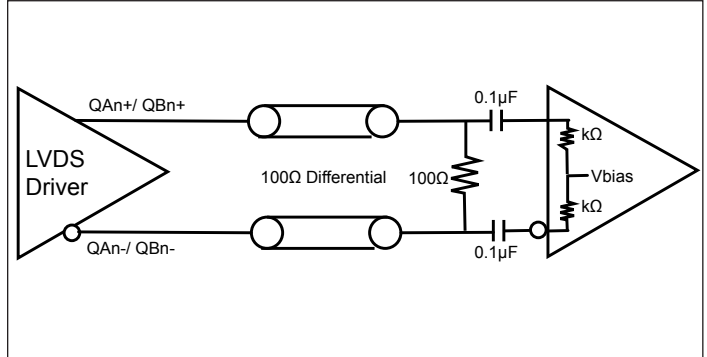
**LVPECL, DC Couple, Thevenin Equivalent**



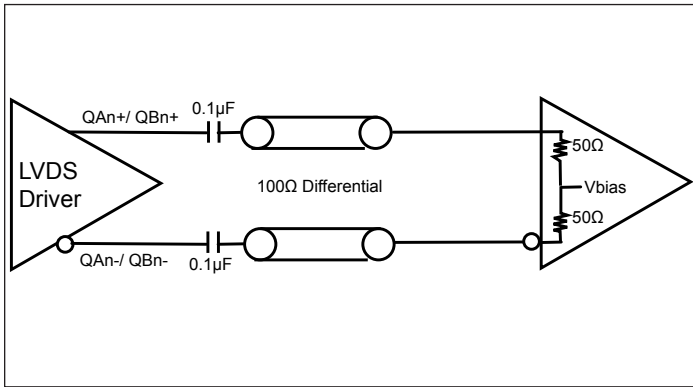
### LVDS DC Couple



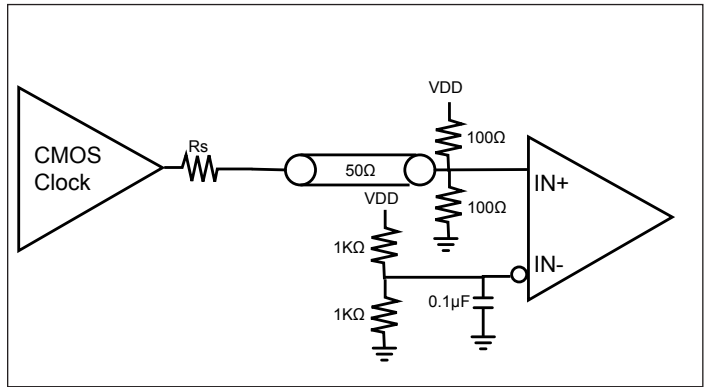
### LVDS AC Couple at Load



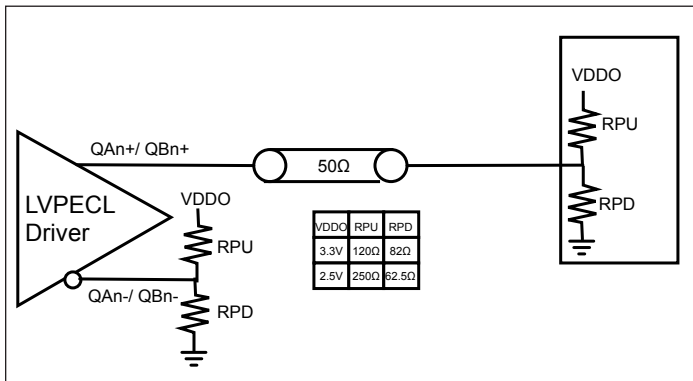
### LVDS AC Couple with Internal Termination



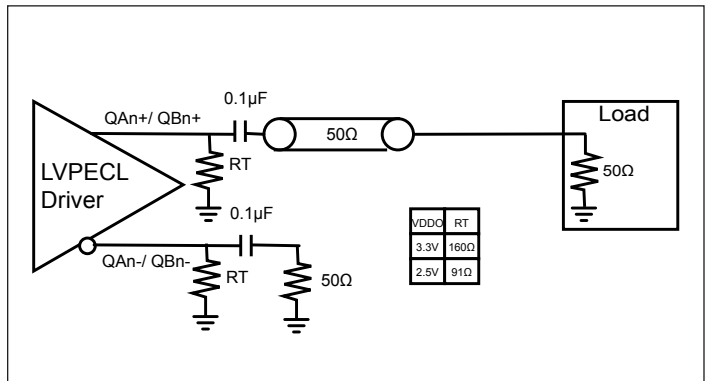
### Single Ended LVPECL, DC Couple



### Single Ended LVPECL, DC Couple, Thevenin Equivalent

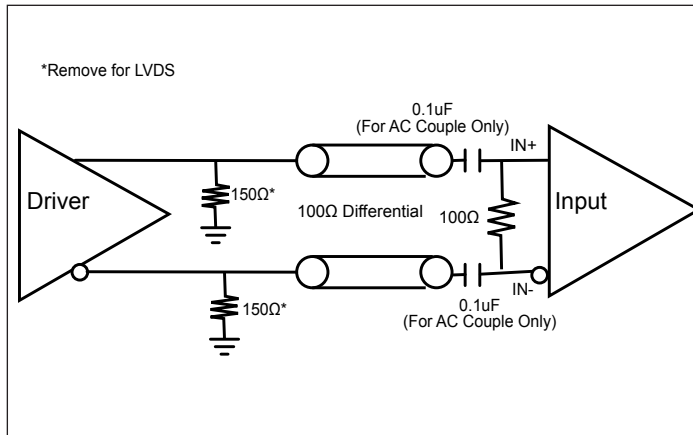


### Single Ended LVPECL, AC Couple, Thevenin Equivalent

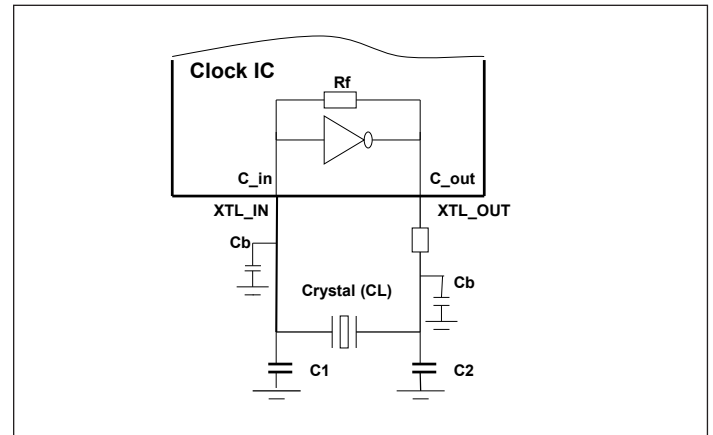


**PI6C492150xTQ**

## LVPECL/ LVDS AC and DC Input



## Clock IC Crystal Input Guide

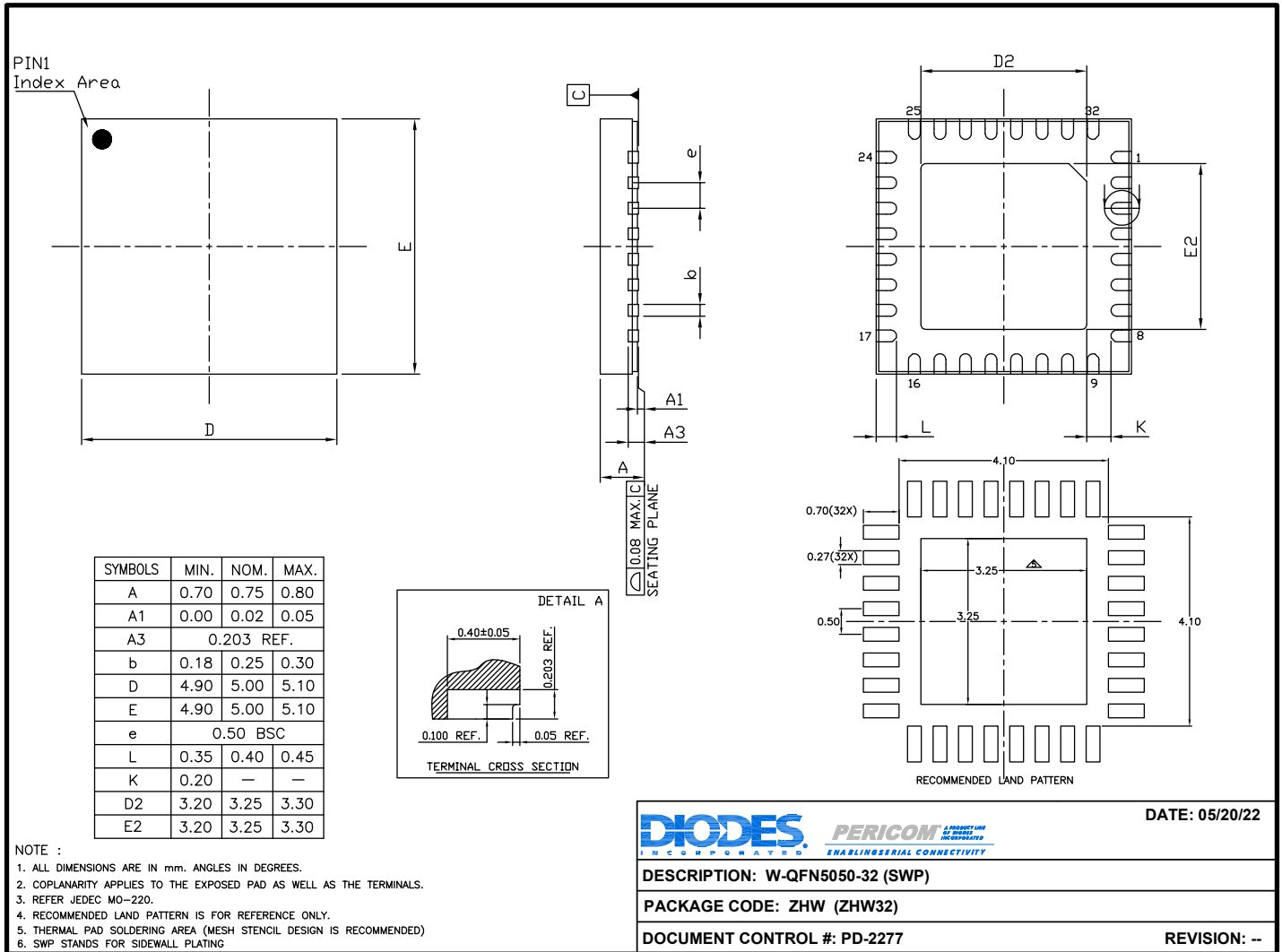


## Part Marking

Top mark not available at this time. To obtain advance information regarding the top mark, please contact your local sales representative.

## Packaging Mechanical

### 32-WQFN (ZHW)



For latest package info.

please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

## Ordering Information

| Ordering Code       | Package Code | Package Description            | Operating Temperature |
|---------------------|--------------|--------------------------------|-----------------------|
| PI6C4921502TQ1ZHWEX | ZHW          | 32-contact, W-QFN5050-32 (SWP) | -40°C to 125°C        |
| PI6C4921504TQ1ZHWEX | ZHW          | 32-contact, W-QFN5050-32 (SWP) | -40°C to 125°C        |

### Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Q = Automotive Compliant
5. 1 = AEC-Q100 Grade Level
6. E = Pb-free and Green
7. X suffix = Tape/Reel

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